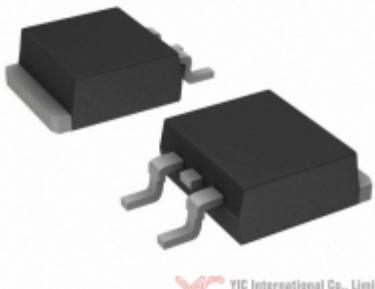


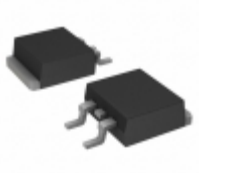


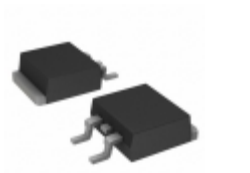
	<h2 style="color: #E67E22;">HGT1S7N60C3DS9A</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: HGT1S7N60C3DS9A
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: IGBT 600V 14A 60W TO263AB
	Datenblätter:  HGT1S7N60C3DS9A.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 5562 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	HGT1S7N60C3DS9A
Hersteller	Fairchild/ON Semiconductor
Beschreibung	IGBT 600V 14A 60W TO263AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs-
Teilstatus	5562 pcs Stock
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-
Befestigungsart	Surface Mount
Leistung - max	60W
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	TO-263AB
Rückwärts-Erholzeit (Trr)	37ns
Strom - Kollektor (Ic) (max)	14A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	2V @ 15V, 7A
Strom - Collector Pulsed (Icm)	56A
Schaltenergie	165µJ (on), 600µJ (off)
Gate-Ladung	23nC
Td (ein / aus) bei 25 ° C	-
Testbedingung	480V, 7A, 50 Ohm, 15V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 HGT4E20N60A4DS INTERSIL INTERSIL TO-268	 HGT1S7N60C3DS AMI Semiconductor / ON Semiconductor IGBT 600V 14A 60W TO263AB	 HGT1S7N60C3DS Fairchild/ON Semiconductor IGBT 600V 14A 60W TO263AB	 HGT1S7N60B3S INTERSIL HGT1S7N60B3S INTERSIL
 HGT4E30N60C3DS Intersil Intersil TO-268	 HGT4E40N60B3S Intersil Intersil TO-268	 HGTD1N120B FAIRCHLD HGTD1N120B FAIRCHLD	 HGT1S7N60C3DS9A AMI Semiconductor / ON Semiconductor IGBT 600V 14A 60W TO263AB

heiße Teile

Mehr

 HGT1S14N41G3VLS9A	 HGT1S15N120C3ST	 HGT1S1N120CNDST	 HGT1S20N36G3VLS	 HGT1S20N36G3VLSR4737
 HGT1S20N60A4S9A	 HGT1S20N60A4S9A	 HGT1S20N60C3R	 HGT1S20N60C3RS	 HGT1S2N120CN
 HGT1S2N120CN	 HGT1S3N60A4DS	 HGT1S3N60A4DS9A	 HGT1S3N60A4DS9A	 HGT1S3N60B3DS
 HGT1S3N60C3DS9A	 HGT1S7N60A4DS	 HGT1S7N60A4DS	 HGT1S7N60A4DS.G7N60A4D	 HGT1S7N60A4DS9A
 HGT1S7N60A4S9A	 HGT1S7N60B3	 HGT1S7N60B3DS	 HGT1S7N60B3S	 HGT1S7N60C3DS9A
 HGTD1N120BNS9A	 HGTD1N120BNS9A	 HGTG10N120BND	 HGTG10N120BND	 HGTG11N120CN
 HGTG11N120CN	 HGTG11N120CND	 HGTG11N120CND	 HGTG12N60A4	 HGTG12N60A4
 HGTG12N60A4D	 HGTG12N60A4D	 HGTG12N60B3D	 HGTG12N60C3D	 HGTG12N60C3D
 HGTG18N120BN	 HGTG18N120BN	 HGTG18N120BND	 HGTG18N120BND	 HGTG20N120CND
 HGTG20N120E2	 HGTG20N50C1D	 HGTG20N60	 HGTG20N60A4	 HGTG20N60A4

Contact us: Info@Y-IC.com

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